

**IN THE CLAIMS:**

Please cancel claims 1-22, without prejudice to or disclaimer of the subject matter recited therein.

Please add claims 23–45 as follows:

**LISTING OF CURRENT CLAIMS**

Claims 1-22. (Canceled)

23. (New) A method to control growth of a magnetic alloy-encapsulated carbon-base nanostructure, comprising:

microwave plasma electron cyclotron resonance chemical vapor depositing an additive and a catalyst on a substrate at a power of 500W - 5000W, a working pressure of less than  $5 \times 10^{-3}$  Torr, and under a magnetic field;

plasma pretreating said substrate by:

biasing with a direct current;

heat treating at a temperature of 400 °C - 850 °C; and

etching said substrate; and

reacting said substrate with a gas and post-treating under said magnetic field.

24. (New) The method according to claim 23, wherein said catalyst and said additive comprise a magnetic metal or an alloy thereof.

25. (New) The method according to claim 23, wherein said catalyst comprises a carbon-soluble metal, an alloy thereof, or a nonmetal.

26. (New) The method according to claim 23, wherein said catalyst comprises

a permanent magnetic rare earth element alloy having carbon solubility.

27. (New) The method according to claim 23, wherein said catalyst comprises a lanthanide or an alloy thereof.

28. (New) The method according to claim 23, wherein said additive comprises copper, gold, platinum or a lanthanide.

29. (New) The method according to claim 25, wherein said additive comprises copper, gold, nitrogen, chromium, boron, titanium, vanadium, zirconium, yttrium or a lanthanide.

30. (New) The method according to claim 23, wherein plasma pretreating changes the size, shape and activity of said catalyst.

31. (New) The method according to claim 23, wherein plasma pretreating controls the size, shape, and directional growth of said carbon-base nanostructure.

32. (New) The method according to claim 23, wherein said substrate comprises a silicon wafer, a stainless steel or a quartz glass.

33. (New) The method according to claim 23, wherein plasma pretreating further comprises physical vapor depositing, chemical vapor depositing, electrochemically plating, coating, or transfer printing.

34. (New) The method according to claim 33, wherein said physical vapor depositing comprises sputtering or evaporating.

35. (New) The method according to claim 33, wherein said chemical vapor depositing comprises plasma enhanced chemical vapor depositing.

36. (New) The method according to claim 33, wherein said electrochemically plating comprises electroplating or electroless plating.

37. (New) The method according to claim 33, wherein said coating said substrate with a metal salt or an alloy thereof of said catalyst comprises rotating coating or immersion plating, then heating said catalyst, and reducing with hydrogen.

38. (New) The method according to claim 33, wherein said transfer printing with a metal salt or an alloy thereof of said catalyst comprises forming a rubber elastomer on said substrate, then heating said catalyst, and reducing with hydrogen.

39. (New) The method according to claim 33, wherein said substrate comprises a catalyst metal thin layer or grain layer at a surface by a photo engraving process, an electron beam lithography, a printing, a transfer printing, or an ion implantation.

40. (New) The method according to claim 23, wherein said substrate comprises a uniform thin layer pattern or a grain layer pattern.

41. (New) The method according to claim 23, wherein said substrate comprises a non-uniform thin layer pattern or grain layer pattern.
42. (New) The method according to claim 23, wherein said gas comprises a carbon-containing gas or a nitrogen-containing gas.
43. (New) The method according to claim 42, wherein said carbon-containing gas comprises methane, ethane, propane, acetylene, benzene or a mixture thereof.
44. (New) The method according to claim 42, wherein said nitrogen-containing gas comprises ammonia, nitrogen, an amine of methane, ethane, propane, acetylene, or benzene, or a mixture thereof.
45. (New) The method according to claim 23, wherein said catalyst comprises iron, cobalt, nickel, an iron-platinum alloy, a cobalt-platinum alloy, silicon,  $\text{Nd}_2\text{Fe}_{14}\text{B}$ , or  $\text{Sm}(\text{Co},\text{Cu})_5$ .